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# A High-Transmittance Frequency-Selective Risorber Based on Dipole Arrays

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**ABSTRACT** This paper presents a frequency-selective risorber whose transmission window locates at the higher frequency of absorption band. The accomplished risorber is composed of dipole-like and slot arrays, and has realized the transmissive/absorptive performance. In every unit cell, each pair of dipole-like elements connected by vias is printed on the two sides of the substrate, and the coupling between long and short dipoles is suppressed by this structure. A guiding circuit is studied based on the analysis of the current path, and the insertion loss of transmission window is significantly reduced by the surface current at the pass-band that is hindered to pass through lossy elements. The presented risorber acts as an absorber at the low frequencies, while providing a high transmittance window at 5.6 GHz. This design is elaborately optimized to achieve low reflection and angle-insensitive performance. Finally, the presented structure is validated by numerical simulations and experimental measurements. This risorber could be used for secrecy communications among stealth facilities while providing stable broad-band absorptive properties.

**INDEX TERMS** Absorption, frequency-selective risorber, high transmittance, low reflection.

## I. INTRODUCTION

A stealth system plays a crucial role in the competition of military industry. In the past, outstanding frequency selective and spatial filtering characteristics of frequency selective surfaces (FSS) have attracted a lot of interest of researchers [1]–[2], and have been utilized to avoid the potential threat from a hostile radar [3]–[5]. The detection power is reflected to other directions and would not influence the communication performance. As the development of detection radar system, the power reflected to other directions could be detected by a multistatic radar system. By inserting lossy elements and adding a reflection layer, an FSS can be structured as a frequency-selective absorber (FSA) [6]–[9]. An FSA features high absorptivity, so that less power is reflected within its operation band. However, the communication ability is limited by the covering FSA, and for that reason, frequency-selective risorbers (FSR) with good

absorptive/transmissive performance have extensively been studied in recent years [10].

The difficulty is that the high insertion loss caused by a lossy FSA cannot be eliminated simply by removing the backed reflection layer, since the power is consumed by the lossy elements. The low-pass characteristic of strip-type FSS has been used to constitute a risorber in some recent designs [11]–[15]. By combining with the band-pass slot-type FSS, a transmission window is realized in low frequencies and the operation characteristic at the frequencies above the pass-band is similar to that of an absorber. Furthermore, several risorbers whose pass-band locates at the frequencies above the absorption band have been proposed [16]–[17]. Other structures in [18]–[19] have allowed the incident power of higher frequency to pass by using distributed inductive and capacitive (*LC*) elements. A band-pass risorber has been realized by using series lumped reactance elements in [20]. The incident wave out of the pass-band is absorbed, while

the reflection over the whole operation band is reduced. Risorbers composed of 3-D unit cell have been suggested in [21] and [22], the transmission band is expanded in these designs, while the wide-band absorptive performance cannot be provided at the same time. Few works realized a transmission window which locates at the frequencies above the stop-band in all of the designs above. For designs featuring a transmission window at high frequencies, the absorption band at low frequencies is relatively narrow, or strong reflection is introduced between the pass-band and stop-band.

The aim of this work is to design a new risorber with a high transmittance window whose frequencies locate above the absorption band. The reflection within the operation band should be reduced while absorbing wide-band incident power. Based on our recent work [23], the precondition of absorptive/transmissive performance is studied using the  $ABCD$  and  $|S|$  matrices. A guiding circuit is presented in order to realize the desired performance. Generally, for most risorbers, the transmission window is generated by  $LC$  elements. Different from the previous designs, a new lossy array is presented and designed to form the risorber. This array is constituted by two pairs of dipole-like elements. For that reason, the complexity and cost of fabrication could be reduced, while introducing few uncertainty factors caused by lumped reactance elements. Meanwhile, the transmission window with low insertion loss is realized with  $0^\circ$ - $45^\circ$  incidence. Furthermore, the presented structure is validated by simulated and experimental results.

## II. EQUIVALENT CIRCUIT ANALYSIS

The profile view of a risorber structure is illustrated in Fig. 1. Generally, the risorber is composed of lossy and lossless layers, which are connected by a spacer with thickness  $t$ . A risorber should function as an absorber at the stop-band, and be transparent at the transmission band. The low reflection over the operation band is realized to achieve stealth performance. Two periodical FSSs can be equivalent to branch circuits, and cascade with a transmission line which is the equivalent circuit of the spacer. The impedance of the lossy layer and lossless layer is expressed by  $Z_a$  and  $Z_b$ , respectively.  $Z_0$  and  $Z_1$  denote the characteristic impedance of the open space and the spacer, respectively. According to the above discussion, the  $ABCD$  matrix of the network can be written as [20]:

$$\begin{aligned} & \begin{bmatrix} A & B \\ C & D \end{bmatrix} \\ &= \begin{bmatrix} 1 & 0 \\ 1/Z_a & 1 \end{bmatrix} \begin{bmatrix} \cos \beta t & jZ_1 \sin \beta t \\ j(1/Z_1) \sin \beta t & \cos \beta t \end{bmatrix} \begin{bmatrix} 1 & 0 \\ 1/Z_b & 1 \end{bmatrix} \\ &= \begin{bmatrix} j\frac{Z_1}{Z_b} \sin \beta t + \cos \beta t & jZ_1 \sin \beta t \\ j\frac{Z_1^2 + Z_a Z_b}{Z_1 Z_a Z_b} \sin \beta t + \frac{Z_a + Z_b}{Z_a Z_b} \cos \beta t & j\frac{Z_1}{Z_b} \sin \beta t + \cos \beta t \end{bmatrix} \end{aligned} \quad (1)$$

where  $\beta = 2\pi/\lambda_0$ , and  $\lambda_0$  is the wavelength of open space. Generally, the value of  $Z_1$  is selected same as  $Z_0$  for a

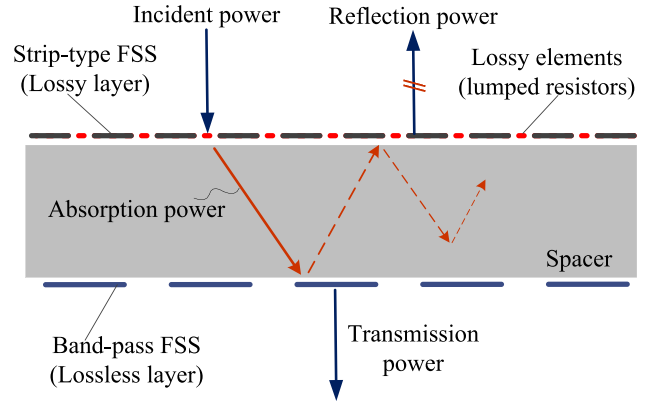


FIGURE 1. Side-view of a risorber structure.

simplified calculation purpose. The expressions of  $|S_{21}|$  and  $|S_{11}|$  could be obtained through the  $ABCD$  matrix and are expressed as follows [24]:

$$\begin{aligned} |S_{21}| &= \left| \frac{2}{A + B/Z_0 + CZ_0 + D} \right| \\ &= \left| \frac{2}{j\left(\frac{Z_0(Z_a + Z_b + Z_0)}{Z_a Z_b} + 2\right) \sin \beta t + \left(\frac{Z_0(Z_a + Z_b)}{Z_a Z_b} + 2\right) \cos \beta t} \right| \end{aligned} \quad (2)$$

$$\begin{aligned} |S_{11}| &= \left| \frac{A + B/Z_0 - CZ_0 - D}{A + B/Z_0 + CZ_0 + D} \right| \\ &= \left| \frac{j\left(\frac{Z_0(Z_a - Z_b - Z_0)}{Z_a Z_b}\right) \sin \beta t - \left(\frac{Z_0(Z_a + Z_b)}{Z_a Z_b}\right) \cos \beta t}{j\left(\frac{Z_0(Z_a + Z_b + Z_0)}{Z_a Z_b} + 2\right) \sin \beta t + \left(\frac{Z_0(Z_a + Z_b)}{Z_a Z_b} + 2\right) \cos \beta t} \right| \end{aligned} \quad (3)$$

At the transmission band,  $|S_{21}| = 1$ . Based on (2), it can be seen that the values of  $Z_a$  and  $Z_b$  should be infinite. When the circuit operates at the stop-band,  $|S_{21}|$  and  $|S_{11}|$  should be zero. According to (2),  $Z_a \times Z_b$  is equal to zero. It is obvious that  $Z_a$  is a complex number with ohmic loss and could not be zero.  $Z_b = 0$  is taken as the solution at the stop-band and is substituted into (3), the following equation is obtained

$$\begin{aligned} |S_{11}| \Big|_{Z_b=0} &= \left| \frac{jZ_0(Z_a - Z_0) \sin \beta t - Z_0 Z_a \cos \beta t}{jZ_0(Z_a + Z_0) \sin \beta t + Z_0 Z_a \cos \beta t} \right| \\ \xrightarrow{Z_a=Z_0, \beta t=\pi/4} |S_{11}| \Big|_{Z_b=0} &= 0 \end{aligned} \quad (4)$$

Therefore, to satisfy the absorption condition, the lossless layer should function as a short circuit at the absorption band. A spacer with  $1/4$  wavelength of absorption frequency thickness should be adopted, and the real part of  $Z_a$  should be close to  $Z_0$ .

The presented risorber should satisfy the constraint conditions discussed above. Moreover, for the reported designs whose transmission window located at the higher frequency of absorption band, the lumped resistors are used as lossy elements to fulfill the absorptive behavior. The transmission coefficient could be influenced due to the surface current

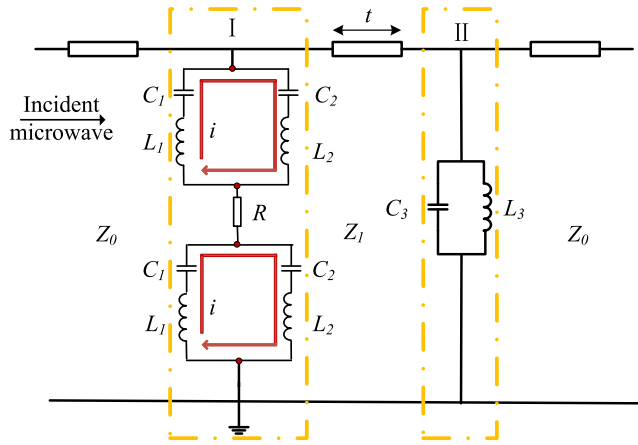


FIGURE 2. Guiding circuit model of the presented risorber.

flowing through the lumped resistors. Therefore, the primary goal of this work is to realize infinite impedance of the lossy layer at the pass-band and reduce the current across the lumped resistors. To realize this goal, a guiding circuit model is studied and shown in Fig. 2. The presented circuit consists of two parts, named as I and II, and connected by a transmission line with the length of  $t$ . The parallel resonance can provide an infinite impedance for FSS structures. In part I, two pairs of identical parallel circuits ( $L_1, C_1$  and  $L_2, C_2$ ;  $L_1 \times C_1 > L_2 \times C_2$ ) placed at the different sides of the resistor to guarantee the resistor is shielded at the pass-band. When the parallel circuits of part I work at the parallel resonance frequency ( $f_1$ ), the current ( $i$ ) is blocked in  $L_1, C_1$  and  $L_2, C_2$ ; therefore, the current through the branch nodes (four red dots in part I) is greatly reduced. Hence, the current through the resistor is significantly reduced at  $f_1$ , and a small insertion loss is introduced within the transmission band. Part II is a parallel branch circuit ( $L_3$  and  $C_3$ ) which functions as a band-pass filter characterized by a wide reflection band. The impedance of part II is zero and infinite at the stop-band and pass-band, respectively. Part I provides an ohmic loss ( $R$ ) to achieve an absorptive performance with the lossless layer at the stop-band, and generates a transmission window at the same time. The part II should be resonant at  $f_1$  in order to enable the incident power to pass through with small insertion loss. This circuit is transparent at  $f_1$  since part I and II are open circuits and the characteristic impedance  $Z_1$  is same as  $Z_0$ .

On the contrary, when the series circuits ( $L_1, C_1$  or  $L_2, C_2$ ) operate at the series resonance frequency ( $f_2$  or  $f_3$ ;  $f_2 < f_3$ ),  $L_1, C_1$  or  $L_2, C_2$  can be equivalent to a shorted circuit. Since the part II presents a reflection feature except around  $f_1$ , the circuit operates as an absorber if an appropriate resistance value is selected. However, it is very difficult to use one resistance value to enable the circuit to match the characteristic impedance of free space at two resonance frequencies. Based on the goal of this work, the absorption band around  $f_3$  is abandoned to realize an absorption band which locates below the pass-band. The resonance frequencies  $f_1, f_2$  and  $f_3$  satisfy

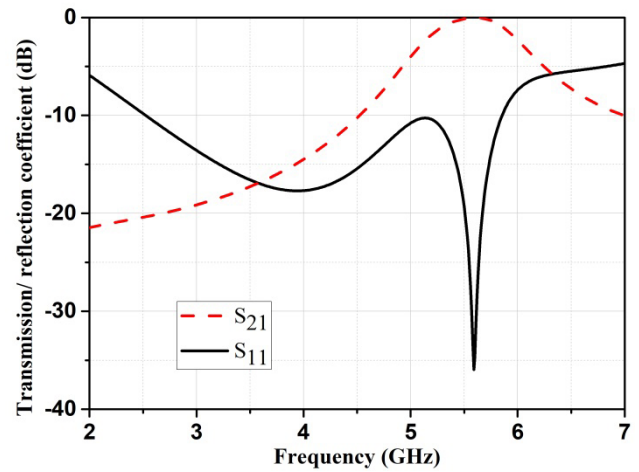


FIGURE 3. Transmissive and absorptive performance of the guiding circuit.

the following relations:

$$\frac{[-j\frac{1-(2\pi f_1)^2 L_1 C_1}{2\pi f_1 C_1}] \cdot [-j\frac{1-(2\pi f_1)^2 L_2 C_2}{2\pi f_1 C_2}]}{[-j\frac{1-(2\pi f_1)^2 L_1 C_1}{2\pi f_1 C_1}] + [-j\frac{1-(2\pi f_1)^2 L_2 C_2}{2\pi f_1 C_2}]}$$

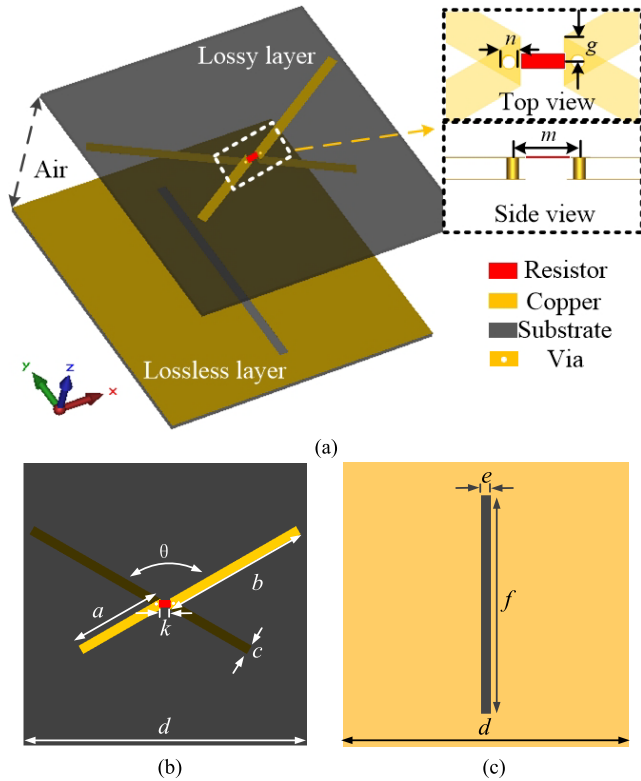
$$= -j\frac{[1 - (2\pi f_1)^2 L_1 C_1] \cdot [1 - (2\pi f_1)^2 L_2 C_2]}{(2\pi f_1)[C_1 + C_2 - (2\pi f_1)^2 L_1 C_1 C_2 - (2\pi f_1)^2 L_2 C_1 C_2]} = 0 \tag{5}$$

$$j\frac{2\pi f_1 L_3}{1 - (2\pi f_1)^2 L_3 C_3} = 0 \tag{6}$$

$$j\frac{1 - (2\pi f_2)^2 L_1 C_1}{2\pi f_2 C_1} = 0 \tag{7}$$

$$j\frac{1 - (2\pi f_3)^2 L_2 C_2}{2\pi f_3 C_2} = 0 \tag{8}$$

The estimated values of  $LC$  elements are obtained by employing the method proposed in [11] and [25]–[28]. It is worth pointing out that the simplest strip and slot FSSs are used to estimate the values of the series circuits ( $L_1, C_1$  or  $L_2, C_2$ ) and parallel circuit ( $L_3, C_3$ ). To obtain the desired risorber performance, we have optimized the estimated circuit element values by using the Tune Parameters Function of Advanced Design System (ADS). Finally, the circuit design has been conducted with following optimized values:  $C_1 = 0.220$  pF,  $L_1 = 8.34$  nH,  $C_2 = 0.106$  pF,  $L_2 = 2.82$  nH,  $C_3 = 0.642$  pF,  $L_3 = 1.269$  nH,  $R = 500 \Omega$ ,  $Z_0 = Z_1 = 377$ , and  $h = 17.3$  mm. The simulated reflection and transmission coefficients of the presented circuit are shown in Fig. 3. It is seen that the desired performance of the risorber is realized by this circuit. The transmission window locates at 5.6 GHz with a small insertion loss of 0.006 dB. Meanwhile, a stop-band is obtained from 2.5 GHz to 4.5 GHz with the reflection lower than  $-10$  dB from 2.5 GHz to 5.8 GHz. At the frequencies above 5.8 GHz, the reflection increases gradually since the value of the resistor is optimized to obtain good absorptive performance around 3.5 GHz.

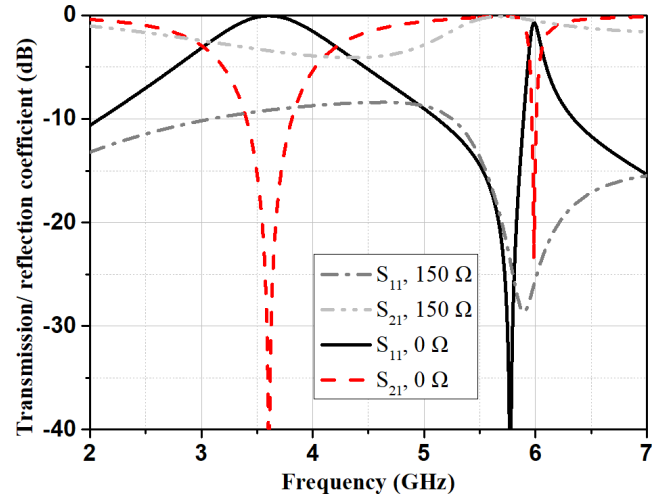


**FIGURE 4.** Unit cells of the presented rASORBER. (a) Perspective view of the presented rASORBER. (b) Top view of the lossy crossed dipole FSS unit cell. (c) Top view of the lossless slot FSS unit cell.

**III. IMPLEMENTATION OF THE RASORBER**

The presented equivalent circuit can be obtained by periodical FSSs. The slot-type FSSs are used here to fulfill the band-pass circuit in part II, and the strip-type FSSs can provide series resonances. The transmission line between part I and II are realized by the air spacer. The geometry of a unit cell of the presented rASORBER is illustrated in Fig. 4. The unit cell is periodic along x- and y-axes, where -z-axis is the direction of incidence. This structure is illuminated by the TM-polarized wave, whose electric-field directed along the x-axis. For the presented design, the thickness of substrates which support both lossy and lossless FSSs is 0.508 mm, and this parameter is chosen by taking both two side copper layers into account. The relative permittivity of the substrate is 2.2, and the distance between two FSS layers is 16 mm. Since two series LC circuits are connected to one side of the resistor, a rotated dipole-like element is selected to overcome the restriction of the physical structure.

The coupling between the connected neighboring long and short dipoles is very strong, so that two pairs of dipoles are placed on the different sides of the lossy layer, and vias are used to conduct the current between both sides. A resistor with 150 Ω is inserted into the gap of dipoles at the front side to connect two pairs of dipoles, meanwhile the gap of the back side is opened. Conversely, the lossless layer is realized by the one-side slot FSS. The equivalent inductance and



**FIGURE 5.** Simulated reflection and transmission results of the lossy layer with 0 Ω and 150 Ω resistors.

capacitance values of the strip-type FSS can be determined from its physical dimensions and the distance between neighboring strip-type FSS, respectively. It is well known that the inductance shows a positive variation tendency with the total length of the dipole, and the capacitance is negatively related to the distance between two neighboring dipoles. Therefore, the long and short dipoles provide resonances at low and high frequencies, respectively. The physical dimensions of unit cells are chosen as follows:  $a = 10$  mm,  $b = 16$  mm,  $c = 1$  mm,  $d = 30$  mm,  $e = 1$  mm,  $f = 23$  mm,  $g = 0.6$  mm,  $k = 1$  mm,  $m = 1.6$  mm,  $n = 0.3$  mm and  $\theta = 120^\circ$

**IV. SIMULATED AND EXPERIMENTAL RESULT ANALYSIS**

The performance of the designed rASORBER is analyzed with a commercial electromagnetic simulation software: CST Microwave Studio. The transmission and reflection results of the lossy layer are plotted in Fig. 5. The lossy FSS serves as a band-stop filter with a resistor of 0 Ω inserted which resonates at 3.6 GHz and 6 GHz. By inserting a resistor of 150 Ω, the quality factor in the stop-bands drops sharply due to the ohmic loss. Nevertheless, the transmission coefficient around the pass-band is almost not influenced, and it provides a potential possibility to realize a transmission window at that frequency. For the lossless FSS layer, it should be optimized to resonate between 5.4 GHz to 5.8 GHz to generate a pass-band.

The joint simulation results of lossy and lossless FSSs are shown in Fig. 6, and the performance under the oblique incidence is explored. As expected, a transmission band is realized at 5.6 GHz with 0.2 dB insertion loss under normal incidence. From 2.8 GHz to 5.7 GHz the reflection is under -10 dB with a fractional bandwidth of 68%, and a low radar cross section (RCS) performance is realized. The absorption band is over 2.8 GHz to 5 GHz, meanwhile there is no harmonic resonance introduced during the operation band. For oblique incidence, the absorptive performance is almost

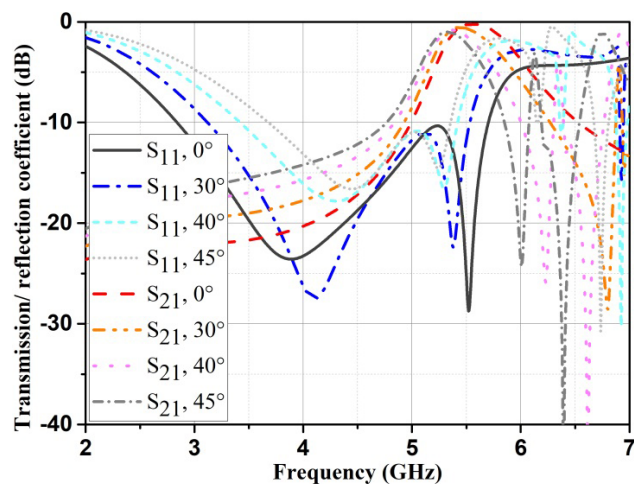


FIGURE 6. Simulated results of the presented raserber under the oblique incidence.

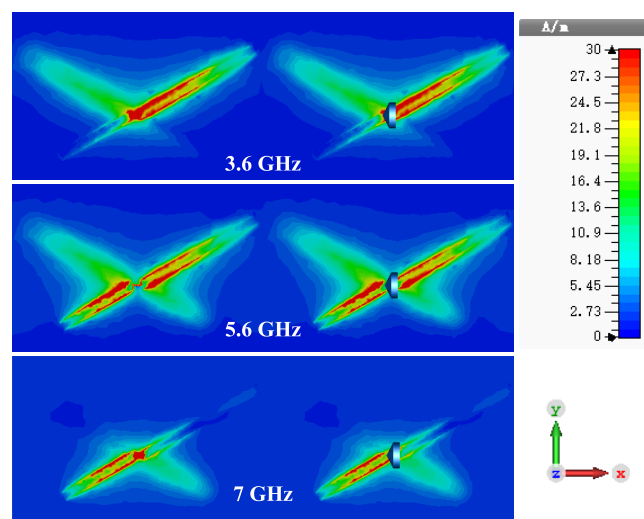


FIGURE 7. The surface current distribution on crossed dipoles with resistors at 3.6 GHz, 5.6 GHz and 7 GHz.

not affected up to 30° and starts to deteriorate after 40°. It is because that the length of the transmission line that is the equivalent circuit of the spacer is sensitive to the oblique incidence, and the input impedance of raserber is changed under the oblique incidence. However, the reflection between the absorption band and transmission band is below -10 dB under 0°-45° incidence. Furthermore, the maximum insertion loss is less than 1 dB under 45° incidence, which could be deemed as a good behavior under the oblique incidence. The transmission peak is slightly shifted towards lower frequencies as the incidence angle increases, since the electrical length is increased under the oblique incidence.

Next, the surface current and electric-field distributions of the raserber are investigated to verify the presented concept. The surface current of dipoles excited by the impinging electric-field is shown in Fig. 7. The lumped resistors of the left dipoles are hidden for observing the current between the

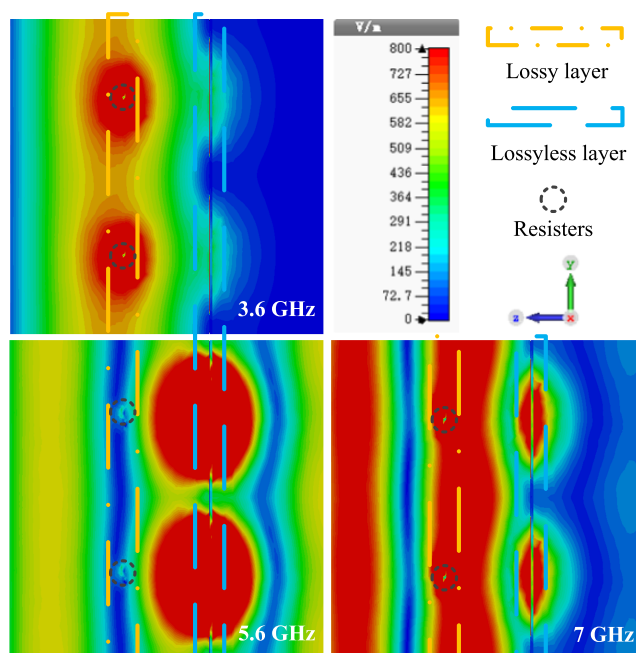
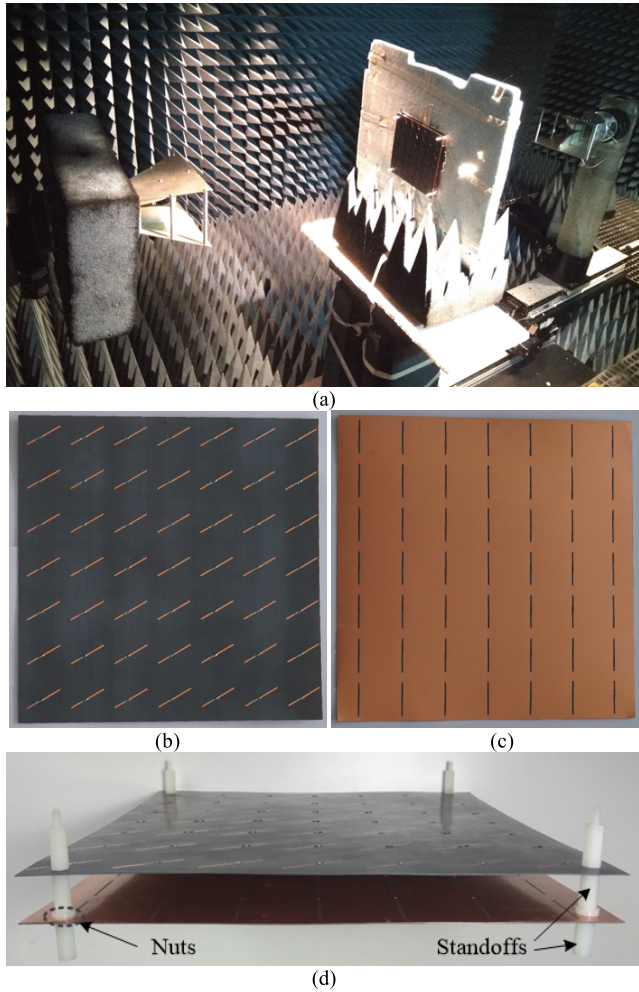


FIGURE 8. The electric-field distribution on the plane of the propagation direction of the incident wave at 3.6 GHz, 5.6 GHz and 7 GHz.

dipoles more clearly. The long dipoles resonate at 3.6 GHz and then there is strong current excited on two long dipoles. The current density flowing across the resistor is so high that most of the incident power is consumed by resistors. At 5.6 GHz, the current through the cascaded resistor is very low even though both long and short dipoles are resonant. The current is blocked in four dipoles, and thus a transmission window with small insertion loss is realized. It is worthwhile to mention that the strong current distribution on two short dipoles at 7 GHz still agrees well with the discussions above.

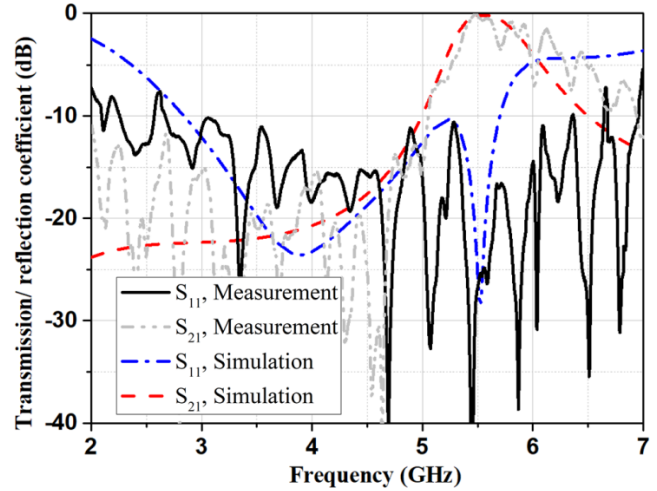
The side view of electric-field distribution along the propagation direction of the incident wave is given in Fig. 8. We observed that at 3.6 GHz, the raserber operates as a high-impedance surface absorber, there is almost no power leaking from the lossless FSS. The incident power is blocked on the lossy FSS layer and absorbed by the inserted lumped resistors of the lossy FSS. The power can penetrate the designed structure at 5.6 GHz, meanwhile the electric-field intensity in front of and beyond the raserber are similar to each other. The strong resonance is introduced by the lossless layer rather than the lossy layer. It indicates that little power is consumed by the presented structure and a high transmittance window is achieved. At 7 GHz, the reflection becomes much stronger than that at 3.6 GHz and 5.6 GHz, and a little power is leaked by the structure at the same time. In other words, these phenomena match the analysis above, and the method can effectively provide a guideline to design a raserber with a high transmittance window.

To validate the designed raserber, an experimental prototype was fabricated with dimensions of 210 mm × 210 mm, and measured in an anechoic chamber. The pictures of the



**FIGURE 9.** Photos of the fabricated rasorber. (a) Photo of the test setup. (b) Top view of the lossy FSS layer. (c) Top view of the lossless FSS layer. (d) Photo of the fabricated rasorber with the standoffs and nuts.

fabricated prototype are shown in Fig. 9. The FSS structures are realized by printed circuit boards (PCB) technique, and both two layers are printed on the F4B substrate whose thickness and relative permittivity are 0.508 mm and 2.2, respectively. The plastic standoffs with a length of 15 mm are used to fix the lossy and lossless FSS layers. Meanwhile, the 0.5 mm thick plastic nuts are inserted between the lossy and lossless FSS layers to realize the air spacer with a thickness of 16 mm. The standoffs and nuts are located at the four corners of the rasorber to reduce the influence on the performance of the rasorber. The thickness of the F4B substrate is negligible compared to the thickness of the air spacer. The simulated and circuit calculation results show that the thin substrate has little effect on the performance of this design. The comparison between measured and simulated results is illustrated in Fig.10, showing that a transmission window is generated around 5.6 GHz and the reflection is controlled at a good level of lower than -10 dB during operation band. Several factors may result in discrepancies between the simulated and experimental results. Although the noise in the experimental



**FIGURE 10.** The comparison between simulation and measurement results.

**TABLE 1.** Performance comparison

| Ref.     | Maximum transmission and $f_T$ | Absorption bandwidth, (-10 dB)           | Strong reflection |
|----------|--------------------------------|--|-------------------|
| [10]     | -1.9 dB, 1 GHz, Sim.           | 8.4-19 GHz, (-20 dB)                     | yes               |
| [11]     | -0.3 dB, 4.6 GHz, Sim.         | 10-18 GHz, (-15 dB)                      | yes               |
| [12]     | -1 dB, 2 GHz, Mea.             | 4.5-12.5 GHz                             | yes               |
| [13]     | -1 dB, 1 GHz, Mea.             | 3-9 GHz                                  | yes               |
| [15]     | -0.5 dB, 0.92 GHz, Mea.        | 3-9 GHz                                  | yes               |
| [17]     | -1.2 dB, 21 GHz, Mea.          | 5-13 GHz                                 | yes               |
| [18]     | -0.15 dB, 10.2 GHz, Mea.       | 3-9 GHz                                  | yes               |
| [19]     | -0.3 dB, 10 GHz, Mea.          | 3.2-8.7 GHz                              | yes               |
| [21]     | -0.2 dB, 2.2 GHz, Mea.         | 0.92-1.43 GHz and 2.84-3.31 GHz, (-7 dB) | no                |
| Our Work | -0.2 dB, 5.6 GHz, Mea.         | 2.8-5 GHz                                | no                |

Ref. = reference number,  $f_T$  = the frequency of maximum transmission coefficient, Mea. = measurement result, Sim. = simulation result, Strong reflection = strong reflection within the operation band.

system, fabrication errors and the influence of the welds have slightly shifted the resonance frequencies and introduced ripples into the results, the operation characteristics are verified.

To clearly demonstrate the performance of our design, a comparison is listed in terms of the maximum transmission and its frequency  $f_T$ , the -10 dB absorption bandwidth, and the strong reflection within operation band in Table I. It is worth to underline that some literatures use other criteria to describe the absorption bandwidth in [10], [11], and [21]. Through the relative relationship between the absorption band and  $f_T$ , it is seen that the absorption bands of many rasorber designs are located above the transmission frequencies. Meanwhile, strong reflection within the operation band is introduced in most designs, and the reflection reduction performance is influenced. The transmission band of our design locates at the frequencies above the absorption band with

a comparatively small insertion loss. Moreover, the strong reflection between the absorption band and transmission band is reduced effectively, and a wide absorption band is realized.

## V. CONCLUSION

A rasorber with a transmission window located at the upper frequencies of the absorption band has been presented in this paper. The dipole elements are used to realize the transmissive behavior, and the complex and costly structures are avoided. Meanwhile, the decoupling structure has been designed to achieve a relatively stable transmissive/absorptive performance. The current flowing across the two sides of the lumped resistor has been reduced by using crossed dipole elements. Therefore, the incident power is allowed to penetrate the presented rasorber with a low insertion loss. The wide absorption bandwidth has been realized with the presented rasorber, and the reflection between the absorption and transmission band is reduced to fulfill the wideband reflection reduction performance. The insertion loss is less than 1 dB under the oblique incidence up to 45°. Finally, the design has been fabricated, measured and validated.

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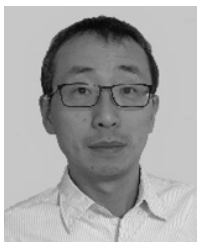


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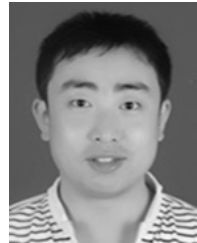
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